

Product Specification

50GHz Dual-window Photodetector

XPDV2320R

PRODUCT FEATURES

- 50GHz typical electrical 3dB bandwidth
- Excellent flat response
- Support of 1310nm and 1550nm
- Well matched 50Ω output
- Unique on-chip integrated bias network

APPLICATIONS

- Communication system at 40Gb/s
- High-speed Lightwave characterization
- Microwave photonics up to 60GHz



The XPDV2320R platform exhibits an optimized frequency response in both, power and phase. It is ideally suited for OC-768/STM-256 long haul systems. The on-chip integrated bias network with optimized design ensures an undisturbed frequency response to the 3dB cut-off frequency and saves costs for internal bias-tees. The hermetic module is especially designed for both optical windows at 1310nm and 1550nm. Further advantage of the waveguide structure is the unbeatable RF high-power behavior. The photodetector shows a linear response up to an optical input power of 10dBm, resulting in a high output voltage swing avoiding the need for electrical amplification.

PRODUCT SELECTION

XPDV2320R-Vx-yy

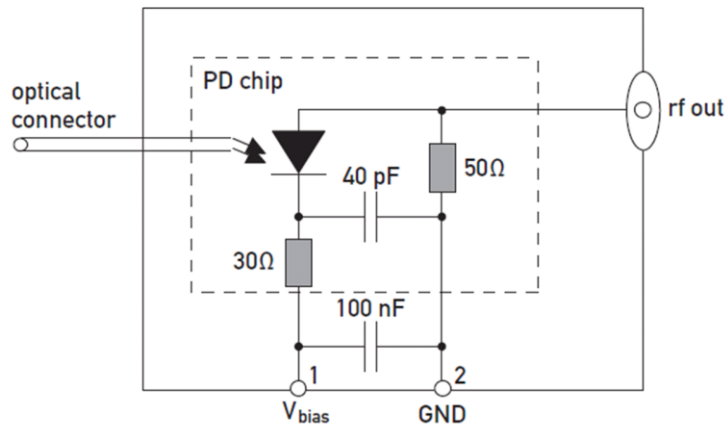
Vx: F = V connector[®] female (standard)
 M = V connector[®] male

yy: FP = FC/PC (standard)
 Available connectors: FA-FC/APC
 Other connectors available upon request

I. Pin Descriptions

# Pin	Symbol	Description
1	V_{bias}	PD bias supply
2	GND	case ground

II. Block Diagram



III. Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Photodiode Bias Voltage	V_{bias}	—	0		4.0	V
Maximum Average Optical Input Power	P_{opt}	Continuous wave (CW) or 40Gb/s NRZ			16	dBm
Maximum Peak Optical Input Power	P_{peak}	Pulse <25ps or 40Gb/s RZ			19	dBm
Electro Static Discharge (ESD)	V_{ESD}	C= 100pF, R= 1.5kΩ HBM	-250		+250	V
Fiber Bend Radius			16			mm

IV. Environmental Specifications

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating Case Temperature	T_{Case}		0		75	°C
Relative Humidity	RH	non condensing	5		85	%
Storage Temperature	T_{sto}		-40		85	°C

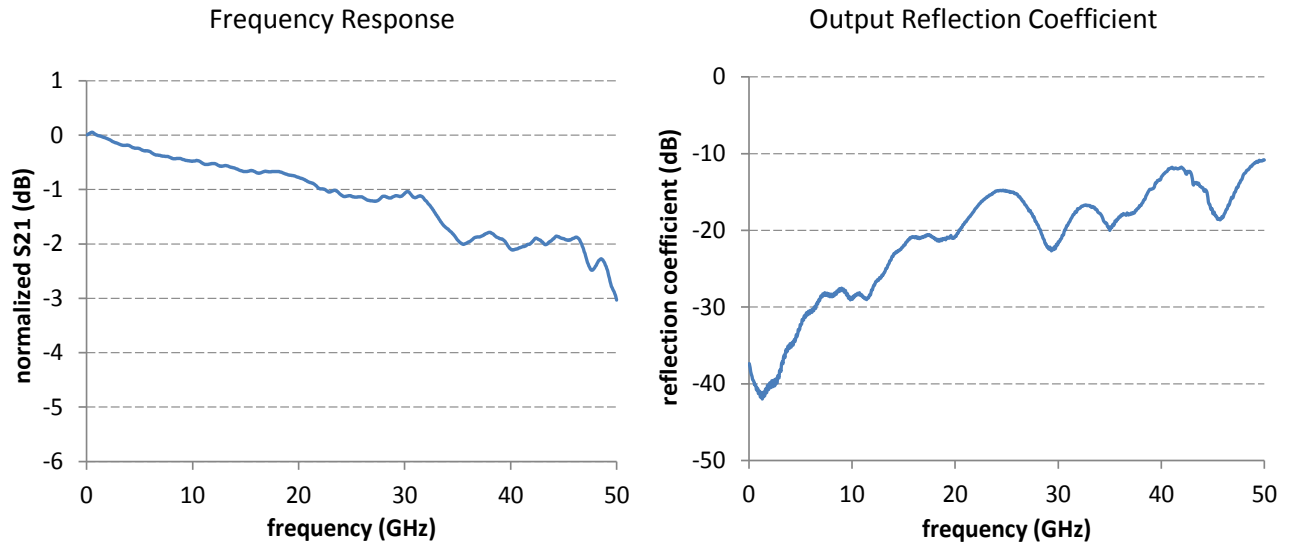
V. Operating Conditions

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating Wavelength Range	λ		1300		1330	nm
			1525		1575	
Average Optical Input Power Range	P_{OPT}				10	dBm
Photodiode Bias Voltage	V_{bias}		2.0	2.8	3.3	V

VI. Electro-Optical Specifications¹

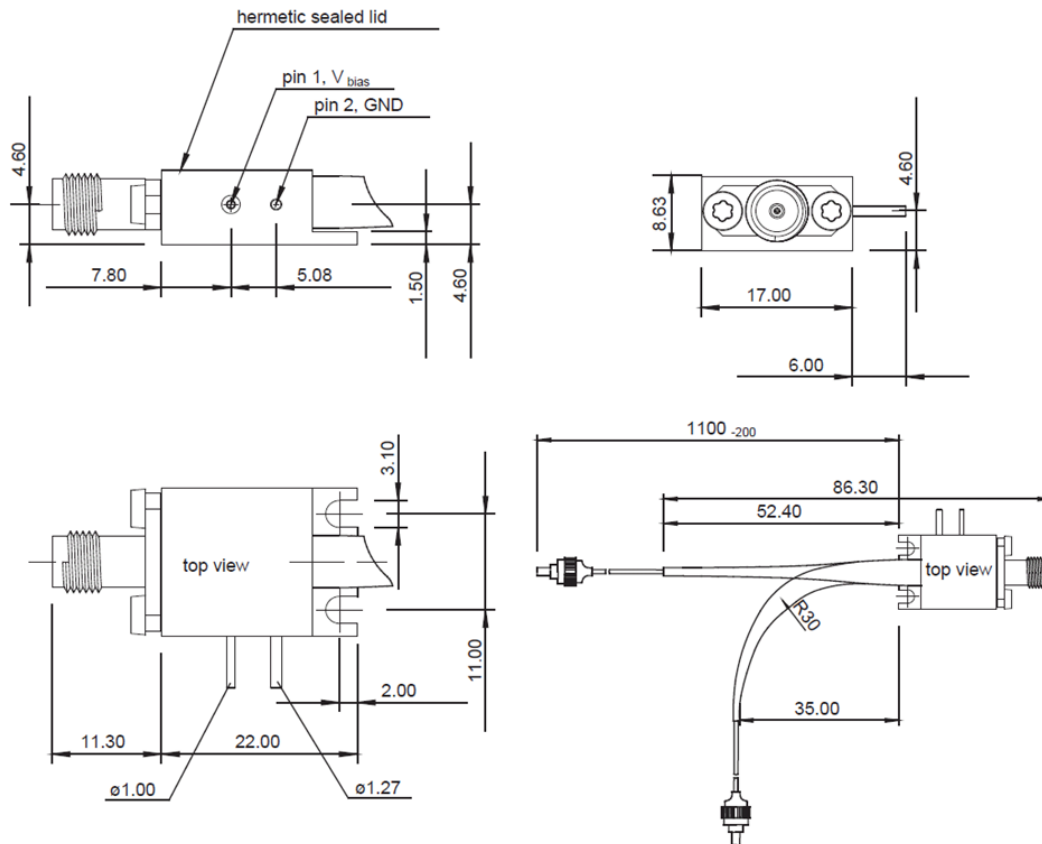
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Photodiode DC Responsivity	R	1310nm	0.30	0.45		A/W
		1550nm	0.45	0.65		
Polarization Dependent Loss	PDL	1310nm		0.4	0.7	dB
		1550nm		0.3	0.6	
Optical Return Loss	ORL	1550nm	27			dB
3dB Cut-off Frequency ²	f_{3dB}		45	50		GHz
Output Reflection Coefficient	S_{22}	0.05 ... 50GHz		-10	-8	dB
Photodiode Dark Current	I_{dark}			5	200	nA
Notes: 1. $\lambda = 1550\text{nm}$ or 1310nm , $V_{\text{PD}} = 3.3\text{V}$, $T_{\text{case}} = 25^\circ\text{C}$, optical input power -3dBm 2. measured using Agilent 86030A 50 GHz Lightwave component analyzer						

VII. Typical Performance Behavior



VIII. Mechanical Specifications

All Dimensions in mm



Parameter	Description
Signal fiber	Standard SMF-28, 900µm loose buffer, yellow

IX. Accessories

Usage of II-VI's individually accessible photodetector power supply (PPS) is recommended, in particular for optimized performance at high optical input levels. As a portable device it provides stable biasing voltage supply and a front display for review on photocurrent.

ORDERING INFORMATION

PPS-03-X

- X: Power supply for XPDV2xxxR/3xxxR series consists of 1x PPS and 1x cable X-type, all PPS versions include two 1.5V batteries and a BNC-to-female connector plug cable



Notes

- Any trademarks used in this document are properties of their respective owners.
- II-VI Incorporated reserves the right to make changes without notice.
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X. Revision History

Revision	Date	Description
A04	2020-01-30	Transition to II-VI template.